

MB14F THRU MB120F

Surface Mount Schottky Bridge Rectifier
Reverse Voltage - 40 to 200 V
Forward Current - 1 A

Features

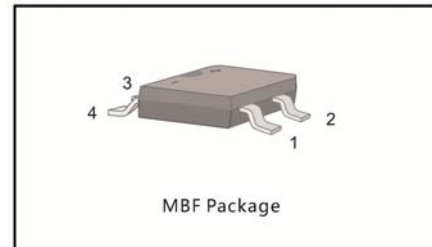
- Glass passivated chip junction
- High Surge Current Capability
- Designed for Surface Mount Application

Mechanical Data

- Case: Molded plastic, MBF
- Terminals: solderable per MIL-STD-750, Method 2026

PINNING

PIN	DESCRIPTION
1	Input Pin (~)
2	Input Pin (~)
3	Output Anode (+)
4	Output Cathode (-)



Absolute Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	MB14F	MB16F	MB18F	MB110F	MB115F	MB120F	Units
	Marking	MB14F	MB16F	MB18F	MB110F	MB115F	MB120F	-
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	40	60	80	100	150	200	V
Maximum RMS Voltage	V_{RMS}	28	42	56	70	105	140	V
Maximum DC Blocking Voltage	V_{DC}	40	60	80	100	150	200	V
Average Rectified Output Current	$I_{F(AV)}$	1						A
Peak Forward Surge Current 8.3 ms Single Half-sine-wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	40			30			A
Maximum Forward Voltage at 1 A	V_F	0.5	0.7	0.85	0.9			V
Maximum DC Reverse Current at Rated DC Blocking Voltage at $T_a = 25^\circ\text{C}$ at $T_a = 100^\circ\text{C}$	I_R	0.3 10		0.2 5	0.1 2			mA
Typical Junction Capacitance ¹⁾	C_J	110	80					pF
Typical Thermal Resistance ²⁾	$R_{\theta JA}$	115						°C/W
Junction Temperature	T_j	- 55 to + 125						°C
Storage Temperature Range	T_{stg}	- 55 to + 150						°C

¹⁾ Measured at 1MHz and applied reverse voltage of 4 V D.C.

²⁾ Mounted on glass epoxy PC board with 4 X (5 X 5 mm²) copper pad.

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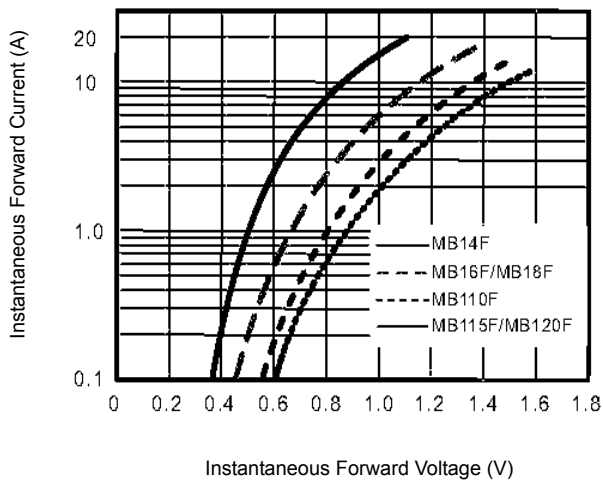


Figure 1. Typical Forward Characteristics

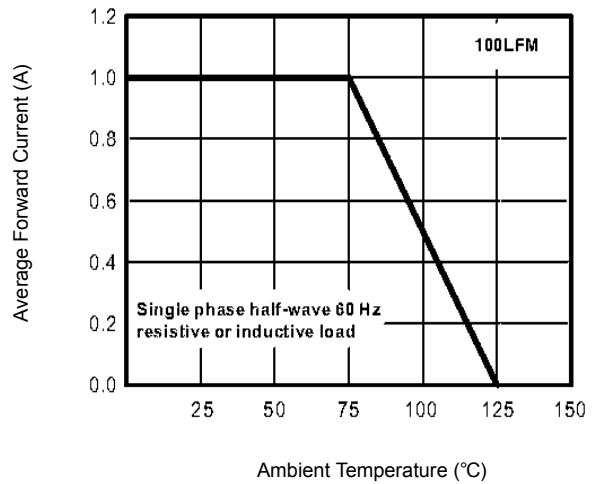


Figure 2. Forward Current Derating Curve

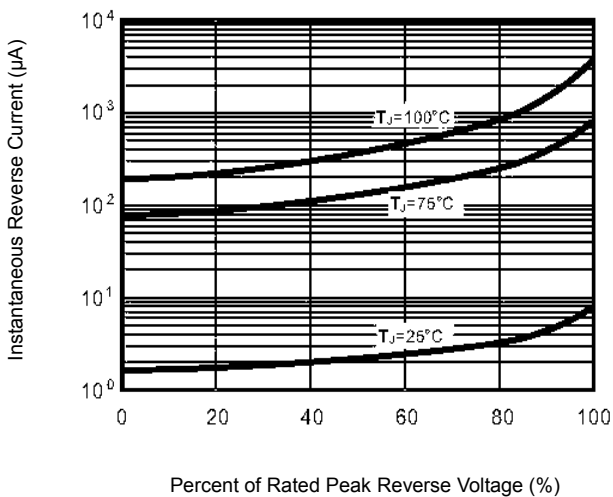


Figure 3. Typical Reverse Characteristics

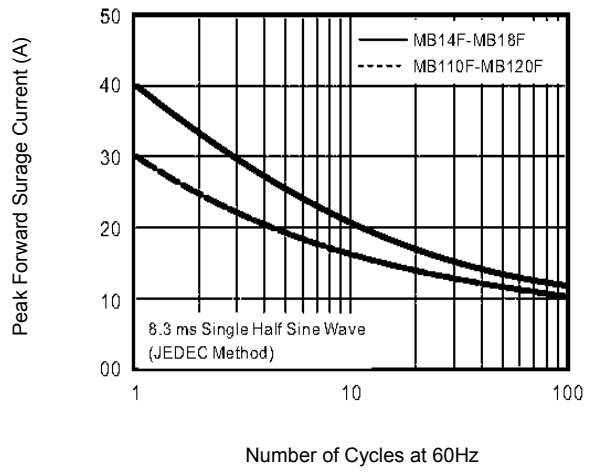


Figure 4. Maximum Non-Repetitive Peak Forward Surge Current

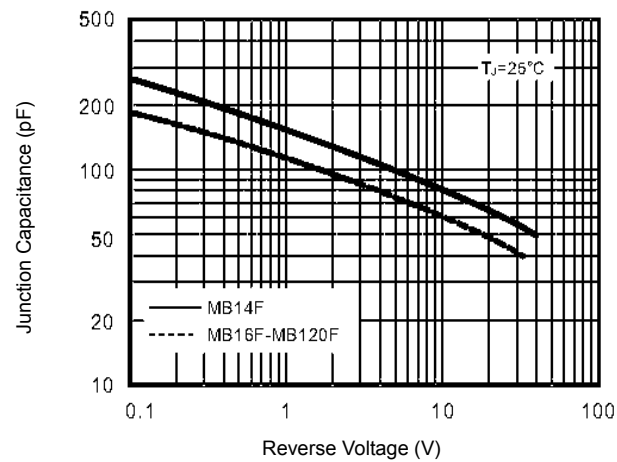


Figure 5. Typical Junction Capacitance

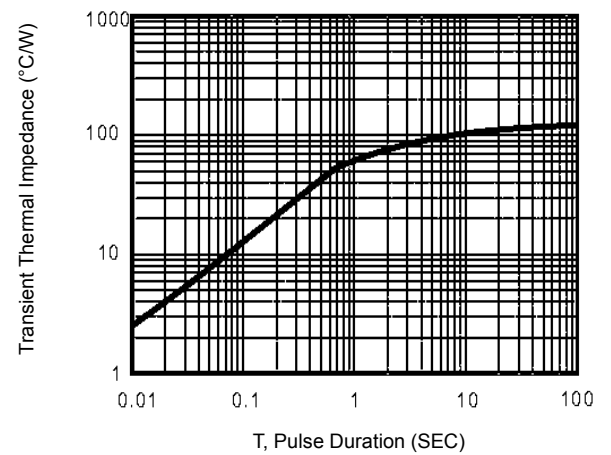


Figure 6. Typical Transient Thermal Impedance

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 ISO 9001 : 2008 Certificate No. 5014012
 OHSAS 18001 : 2007 Certificate No. 0519508006
 IECQ QC 080000 Certificate No. ECN10011002

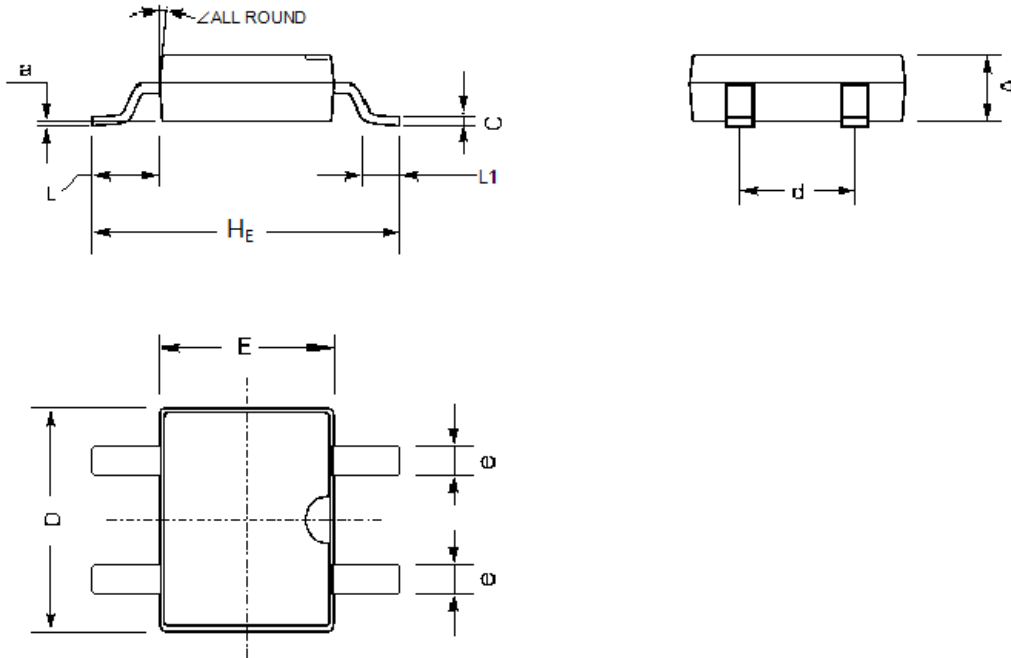
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PACKAGE OUTLINE

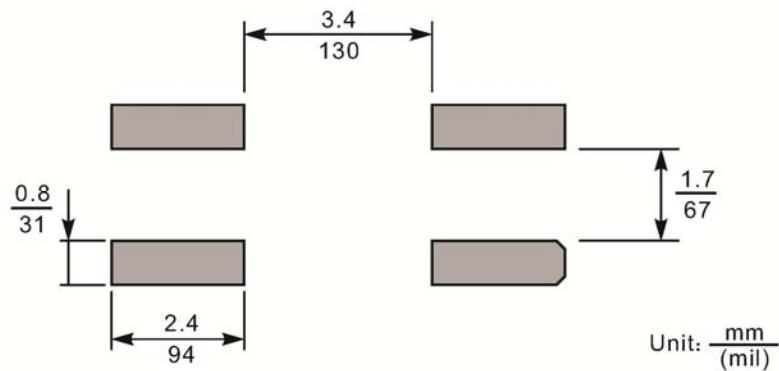
MBF

Plastic surface mounted package; 4 leads



UNIT	A	C	D	E	HE	d	e	L	L1	a	∠
mm	1.6	0.22	5	4.1	7	2.7	0.7	1.7	1.1	0.2	7°
	1.2	0.15	4.5	3.6	6.4	2.3	0.5	1.3	0.5	0	

Recommended Soldering Footprint



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